3.2mm UV Silicon PIN photodiode

Version: 3.1 17-06-01

mA

V

°C

Model: LSSPD-U3.2 Features: High reliability, low dark current 200-1100nm spectral range Active diameter 3.2x3.2mm Hermetic TO5 Can with UV win		08.1	CWFC	cwsc		
Applications:				st sensing		
Optical sensor			CWLC	CWST		
 Optical power meter 				001		
 Industrial automatic control 						
Science analysis and experiment						
Space light detect equipment						
Response spectrum testing						
Absolute maximum ratings:						
parameter	symbol	value	unit			
Operating temperature	Тор	-40~+85	°C			
Storage temperature	Tstg	-40~+100	°C			

16

20

260

Electrical and optical characteristics:(T=25°C)

lf

 V_r

Ts (10s)

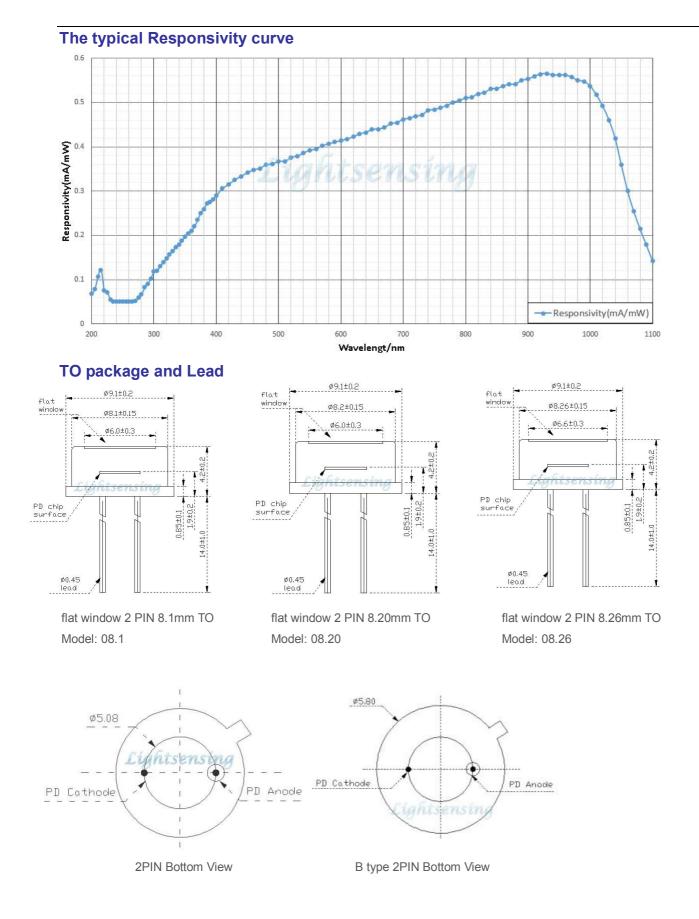
Forward current

Reverse voltage

Soldering temperature(time)

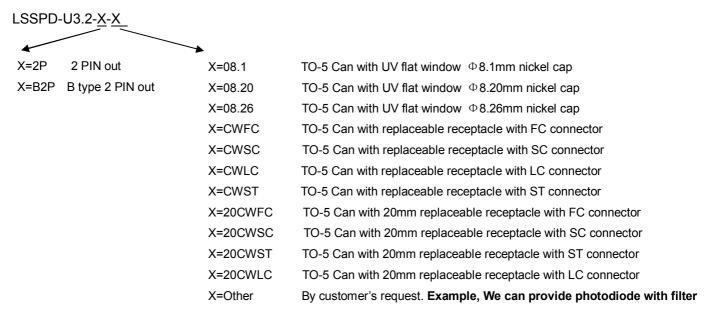
parameter	symbol	unit	Value (typ.)	
Active diameter	Φ	mm	3.2x3.2	
Spectral range	λ	nm	200-1100	
Responsivity	Re(VR=0V,λ=200nm)	mA/mW	0.08	
	Re(VR=0V,λ=405nm)	mA/mW	0.28	
	Re(VR=0V,λ=650nm)	mA/mW	0.43	
	Re(VR=0V,λ=905nm)	mA/mW	0.55	
	Re(VR=0V,λ=1064nm)	mA/mW	0.22	
Response time	Tr (R _L =50Ω,V _R =5V)	ns	50	
Dark current	ld(VR=0V)	PA	1	
	ld(VR=5V)	рА	200	
Reverse Breakdown voltage	VBR (IR=10uA)	V	40	
Junction capacitance	Cj (f=1MHz, VR=0V)	pF	1500	
	Cj (f=1MHz, VR=5V)	pF	300	
Saturated Optical Power	Ps(VR =5V)	mW	25	
Operating voltage	V _R	V	0-15V	
Shunt resistance	Rsh (VR=10mV)	GΩ	10	
package	Hermetic TO5 Can with UV window or with receptacle			

NOTICE: The above product specifications are subject to change without notice.



Note: In order to get other dimensions, please contact us.

Order information



The cautions

1: The above product specifications are subject to change without notice.

2: The suitable ESD protection is required in storage, transportation and using